



<u>DXT3906</u>

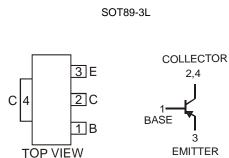
PNP SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DXT3904)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.072 grams (approximate)



Schematic and Pin Configuration

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current – Continuous	Ι _C	-200	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ $T_A = 25^{\circ}C$	PD	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^{\circ}C$	$R_{\theta JA}$	125	°C/W
Operating and Storage Temperature Range	Tj, T _{STG}	-55 to +150	°C

Notes: 1. No purposefully added lead.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

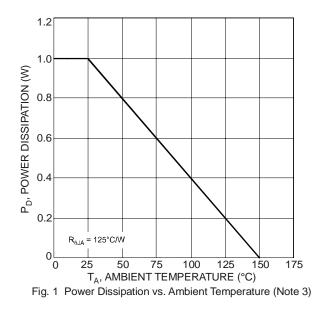
3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

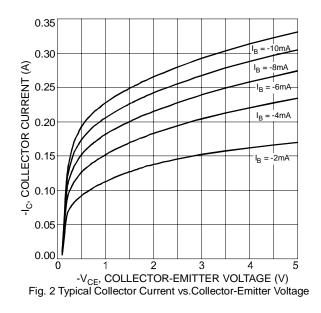


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Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V _(BR) CBO	-40	—	V	$I_{C} = -10 \mu A, I_{E} = 0$	
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40		V	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$	
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0		V	$I_E = -10\mu A, I_C = 0$	
Collector Cutoff Current	I _{CEX}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$	
collector Cuton Cutrent	I _{CBO}		-50	nA	$V_{CB} = -30V, I_E = 0$	
Base Cutoff Current	I _{BL}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$	
ON CHARACTERISTICS (Note 4)				-		
		60			$I_{C} = -100 \mu A, V_{CE} = -1.0 V$	
DC Current Gain		80			$I_{C} = -1.0 \text{mA}, V_{CE} = -1.0 \text{V}$	
	h _{FE}	100	300	—	$I_{C} = -10 \text{mA}, V_{CE} = -1.0 \text{V}$	
		60 30	—		$I_{C} = -50 \text{mA}, V_{CE} = -1.0 \text{V}$	
		30			$I_{\rm C} = -100 {\rm mA}, V_{\rm CE} = -1.0 {\rm V}$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.25	V	$I_{\rm C}$ = -10mA, $I_{\rm B}$ = -1.0mA	
	VCE(SAT)		-0.40	-	I _C = -50mA, I _B = -5.0mA	
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.65 —	-0.85	0.85 V 0.95 V	$I_{\rm C}$ = -10mA, $I_{\rm B}$ = -1.0mA	
5	· BE(SAT)		-0.95		$I_{\rm C} = -50$ mA, $I_{\rm B} = -5.0$ mA	
SMALL SIGNAL CHARACTERISTICS				-		
Output Capacitance	Cobo		4.5	pF	$V_{CB} = -5.0V, f = 1.0MHz, I_E = 0$	
nput Capacitance	C _{ibo}		10	pF	$V_{EB} = -0.5V, f = 1.0MHz, I_C = 0$	
nput Impedance	h _{ie}	2.0	12	kΩ	V _{CE} = -10V, I _C = -1.0mA, f = 1.0kHz	
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴		
Small Signal Current Gain	h _{fe}	100	400			
Output Admittance	h _{oe}	3.0	60	μS		
Current Gain-Bandwidth Product	f _T	250	—	MHz	$V_{CE} = -20V, I_C = -10mA, f = 100MHz$	
Noise Figure	NF		4.0	dB	$V_{CE} = -5.0V, I_{C} = -100\mu A,$	
5				40	$R_S = 1.0 k\Omega$, f = 1.0kHz	
SWITCHING CHARACTERISTICS			1	r	Ι	
Delay Time	t _d		35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$	
Rise Time	tr		35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$	
Storage Time	ts	_	225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$	
Fall Time	t _f		75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$	

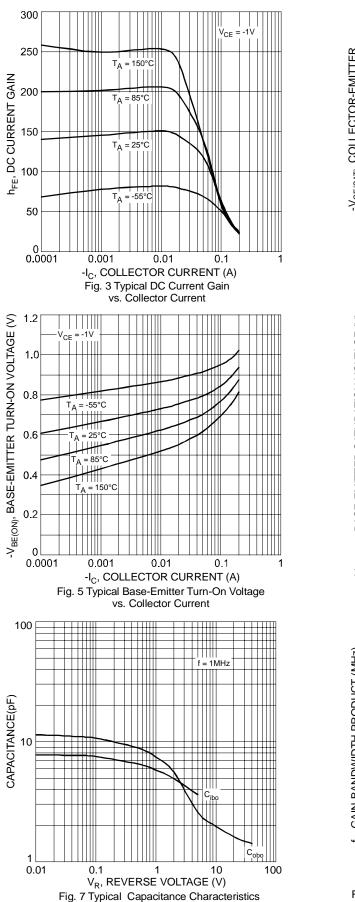
Notes: 4. Measured under pulsed condition. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

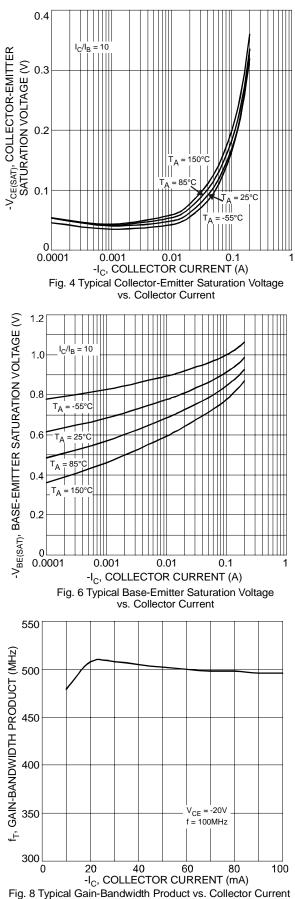






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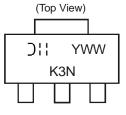


Ordering Information (Note 5)

Device	Packaging	Shipping
DXT3906-13	SOT89-3L	2500/Tape & Reel

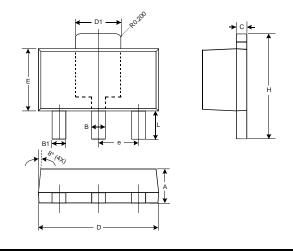
Notes: 5. For packaging details, go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information



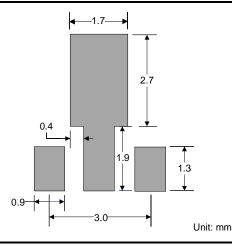
K3N = Product Type Marking Code \Im II = Manufacturer's Marking Code YWW = Date Code Marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

Package Outline Dimensions



	SOT89-3L					
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.45	0.55	0.50			
B1	0.37	0.47	0.42			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.50	1.70	1.60			
Е	2.40	2.60	2.50			
е	_		1.50			
Н	3.95	4.25	4.10			
L	0.90	1.20	1.05			
All Dimensions in mm						

Suggested Pad Layout



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